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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/651,103	08/29/2003	Shoriki Narita	2003_1226	7745
513	7590 07/27/2004		EXAM	INER
WENDEROTH, LIND & PONACK, L.L.P. 2033 K STREET N. W.			ANYA, IGWE U	
SUITE 800			ART UNIT	PAPER NUMBER
	N, DC 20006-1021		2825	

DATE MAILED: 07/27/2004

Please find below and/or attached an Office communication concerning this application or proceeding.

				41		
		Application No.	Applicant(s)	<i>F</i>		
		10/651,103	NARITA ET AL.			
	Office Action Summary	Examiner	Art Unit			
		Igwe U. Anya	2825			
Period fe	The MAILING DATE of this communication a or Reply	ppears on the cover sheet with	h the correspondence address	•		
THE - Exte after - If the - If NC - Failt Any	MAILING DATE OF THIS COMMUNICATION ensions of time may be available under the provisions of 37 CFR of SIX (6) MONTHS from the mailing date of this communication. The period for reply specified above is less than thirty (30) days, a reduce to reply within the set or extended period for reply will, by statuted period for reply within the set or extended period for reply will, by statuted patent term adjustment. See 37 CFR 1.704(b).	I. 1.136(a). In no event, however, may a reply within the statutory minimum of thirty d will apply and will expire SIX (6) MONT ate, cause the application to become ABA	ply be timely filed (30) days will be considered timely. (HS from the mailing date of this communical NDONED (35 U.S.C. § 133).	ntion.		
Status						
1)[🛛	Responsive to communication(s) filed on 29	August 2003.				
		nis action is non-final.				
3)						
Disposit	ion of Claims					
5)□ 6)⊠ 7)□	Claim(s) <u>44-47</u> is/are pending in the application 4a) Of the above claim(s) is/are withdred claim(s) is/are allowed. Claim(s) <u>44-47</u> is/are rejected. Claim(s) is/are objected to. Claim(s) are subject to restriction and the claim(s) are subject to restriction.	awn from consideration.				
Applicat	ion Papers					
10)⊠	The specification is objected to by the Examin The drawing(s) filed on 29 August 2003 is/are Applicant may not request that any objection to the Replacement drawing sheet(s) including the correct The oath or declaration is objected to by the Examination.	e: a) accepted or b) objected or b) objected or b) objected in abeyanced; bection is required if the drawing(s	e. See 37 CFR 1.85(a). s) is objected to. See 37 CFR 1.121	• •		
Priority ι	ınder 35 U.S.C. § 119					
12)⊠ a)∣	Acknowledgment is made of a claim for foreign All b) Some * c) None of: 1. Certified copies of the priority document as: 2. Certified copies of the priority document as: 3. Copies of the certified copies of the priority application from the International Buresee the attached detailed Office action for a list	nts have been received. nts have been received in Ap ority documents have been r au (PCT Rule 17.2(a)).	plication No eceived in this National Stage			
Attachmen	t(s)					
1) 🛭 Notic 2) 🔲 Notic	e of References Cited (PTO-892) e of Draftsperson's Patent Drawing Review (PTO-948)	4) Interview Su	mmary (PTO-413) Mail Date			
3) 🔯 Inforr	nation Disclosure Statement(s) (PTO-1449 or PTO/SB/08 r No(s)/Mail Date <u>8/03, 1/04, 6/04</u> .	5) Notice of Info 6) Other:	ormal Patent Application (PTO-152)			

DETAILED ACTION

Claim Rejections - 35 USC § 102

1. The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

- (b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.
- (e) the invention was described in a patent granted on an application for patent by another filed in the United States before the invention thereof by the applicant for patent, or on an international application by another who has fulfilled the requirements of paragraphs (1), (2), and (4) of section 371(c) of this title before the invention thereof by the applicant for patent.

The changes made to 35 U.S.C. 102(e) by the American Inventors Protection Act of 1999 (AIPA) and the Intellectual Property and High Technology Technical Amendments Act of 2002 do not apply when the reference is a U.S. patent resulting directly or indirectly from an international application filed before November 29, 2000. Therefore, the prior art date of the reference is determined under 35 U.S.C. 102(e) prior to the amendment by the AIPA (pre-AIPA 35 U.S.C. 102(e)).

- 2. Claims 44, and 47 are rejected under 35 U.S.C. 102(e) as being anticipated by Dahimene et al. (US Patent 6198616).
- 3. Dahimene et al. teach a charge-removing unit for a circuit-formed semiconductor comprising a heating and cooling apparatus (126) in contact with the rear of the semiconductor wafer system (fig. 1) through a helium transfer medium, and a temperature controller for the heating and cooling apparatus (col. 5 line 32 col. 6 line 55). The limitations of the intended use were not considered. A recitation with respect to the manner in which a claimed apparatus is intended to be employed does not

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differentiate the claimed apparatus from a prior art apparatus satisfying the claimed structural limitations. Ex Parte Mashm, 2 USPQ F.2d 1647 (1987). Applicant's functional statement does not define any structure, and accordingly cannot serve to distinguish. In re Mason USPQ 127, 44 CCPA (1957).

- 4. Claim 45 is rejected under 35 U.S.C. 102(e) as being anticipated by Fujita et al. (US Patent 6034578).
- 5. Fujita et al. teach a piezoelectric substrate (1) comprising, on a major surface a circuit (fig.2) and a region for charge removal formed of a conductor (7), and dicing lines (9) connected to the region for charge removal (col. 3 line 15 col. 4 line 53).
- 6. Claim 46 is rejected under 35 U.S.C. 102(e) as being anticipated by Hidaka et al. (JP Patent 401077111A).
- 7. Hidaka et al. teach a charge appearance semiconductor, which has electric charge of absolute value no greater than 200 volts stored in the semiconductor after eliminating pyroelectric effect charge (Abstract).
- 8. Art made of record and not relied upon considered pertinent to applicant's disclosure include Hirota et al. (JP 2002203995), and Yamashita (JP 2002009569).
- 9. Any inquiry concerning this communication or earlier communications from the examiner should be directed to Igwe U. Anya whose telephone number is (571) 272-1887. The examiner can normally be reached on M F 8:30am 5:00pm.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Matthew S. Smith can be reached on (571) 272-1907. The fax phone

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number for the organization where this application or proceeding is assigned is 703-872-9306.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

> Igwe U. Anya Examiner Art Unit 2825

IA

July 22, 2004

MATTHEW SMITH SUPERVISORY PATENT EXAMINER TECHNOLOGY CENTER 2800